



**Features**

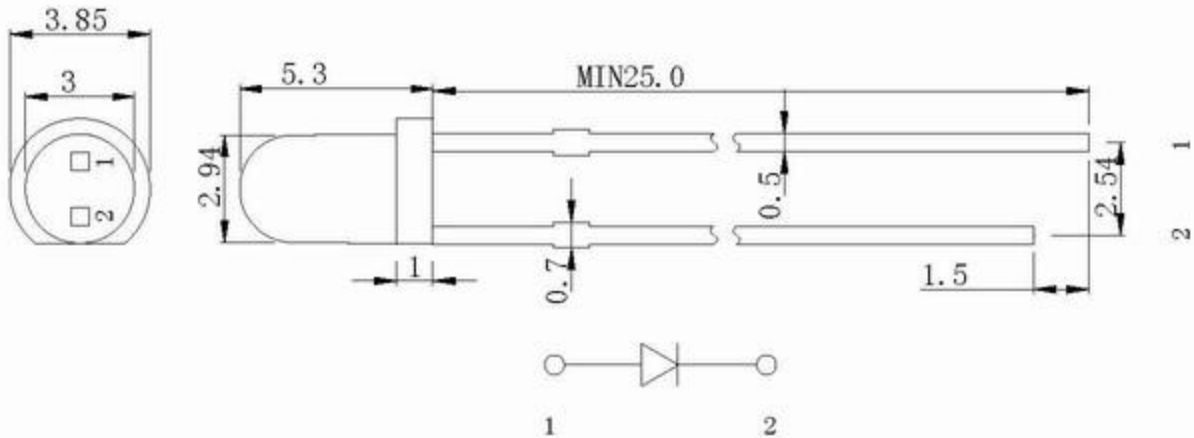
- Mechanically and spectrally matchend to the phototransistor.
- Rohs compliant.



**Package Dimensions**

**Description**

This devices are made with TS GaAs.



Torlerance Grade	Dimension Torlerance (UNIT:mm)			
	0.5~3	3~6	6~30	30~120
Medium(m)	±0.1	±0.2	±0.3	±0.5
Chip		Lens Color		
Material	Emitting Color	Water Clear		
GaAs	/			

**Selection Guide**

Part No	Launch Apart (m) IF=50mA		Viewing Angle
	Min	Typ	2θ1/2
304IR3C-L3	--	10	25

Note:

1. 2θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
2. Tolerance of measurement of luminous intensity±15%.

**Electrical / Optical Characteristics at TA=25°C**

Item	Symbol	Min	Typ	Units	Test Conditions
Forward Voltage	VF	1.2	1.5	V	IF=50mA
Reverse Current	IR	--	20	uA	
Peak Spectral Wavelength	$\lambda D$	--	940	nm	
Spectral Bandwidth	$\Delta \lambda 1/2$	--	50	nm	

Note:

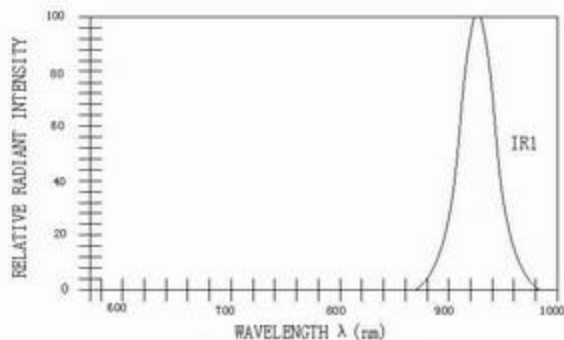
1. Tolerance of measurement of forward voltage±0.1V.
2. Tolerance of measurement of peak Wavelength±2.0nm.

**Absolute Maximum ratings at Ta=25°C**

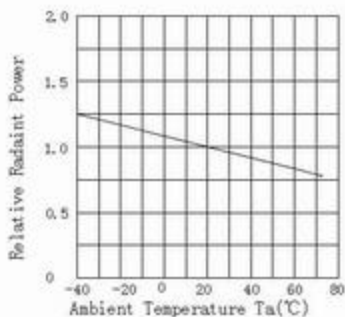
Parameter	Symbol	IR1	Units
Power Dissipation	Pt	100	mW
DC Forward Current	IF	50	mA
Peak Forward Current[1]	$i_{FS}$	300	mA
Operating Temperature		-30°C~80°C	
Storage Temperature		-30°C~80°C	

Note:

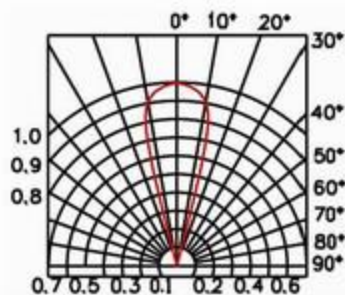
1. IFP Conditions: Pulse Width≤10msec
2. Tsol Conditions: 3mm from the base of the epoxy bulb



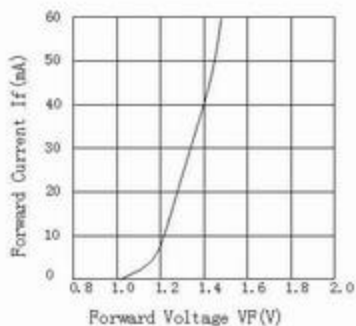
Forward Current vs. Forward Voltage



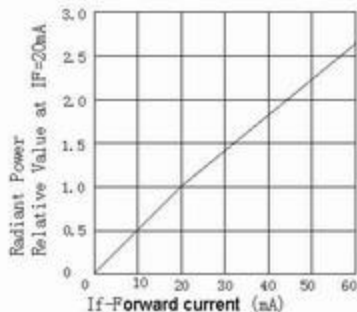
Radint Power Vs. Ambient Temperature



Spatial Distribution



Forward Current Vs. Forward Voltage



Radint Power Vs Forward Current

If special sorting is required (e.g. binning based on forward voltage or radiant intensity/luminous flux), the typical accuracy of the sorting process is as follows:

1. Radiant intensity/Luminous Flux:  $\pm 15\%$ .
2. Forward Voltage:  $\pm 0.1V$ .

Note: Accuracy may depend on the sorting parameters.

## Soldering:

### 1. Manual Of Soldering

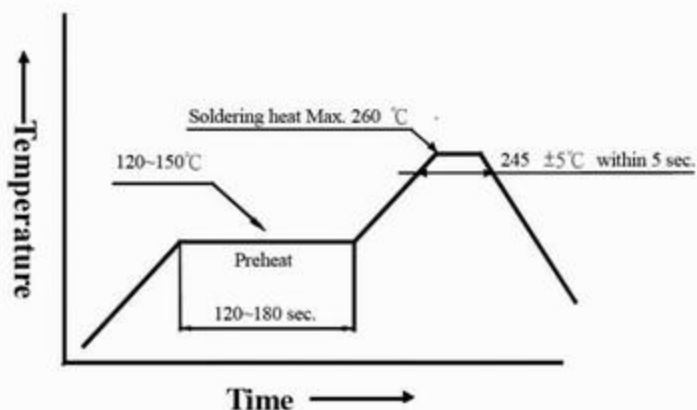
The temperature of the iron tip should not be higher than 260°C(500°F) and Soldering within 3 seconds per solder-land is to be observed.

### 2. DIP soldering (Wave Soldering):

Preheating:120°C~150°C,within 120~180 sec.

Operation heating:245°C±5°C within 5 sec.260°C(Max)

Gradual Cooling (Avoid quenching).



## Handling:

Care must be taken not to cause to the epoxy resin portion of LED while it is exposed to high temperature.

Care must be taken not rub the epoxy resin portion of LED with hard or sharp article such as the sand blast and the metal hook.

Care must be taken there should be more than 3mm from jointing point to the epoxy resin.

## Notes for designing:

Care must be taken to provide the current limiting resistor in the circuit so as to drive the LED within the rated figures .Also caution should be taken not to overload LED with exorbitant voltage at the turning ON and OFF of the circuit.

When using the pulse drive care must be taken to keep the average current within the rated figures .Also the circuit should be designed so as be subjected to reverse voltage when turning off the LED.

## Storage:

In order to avoid the absorption of moisture , it is recommended to solder LED as soon as possible after unpacking the sealed envelope.

If the envelope is still packed to store it in the environment as following:

Temperature:-5°C~45°C(23°F~113°F)Humidity : RH 60% Max.